

635nm 500mw High Power Laser Diode| C-mount Package

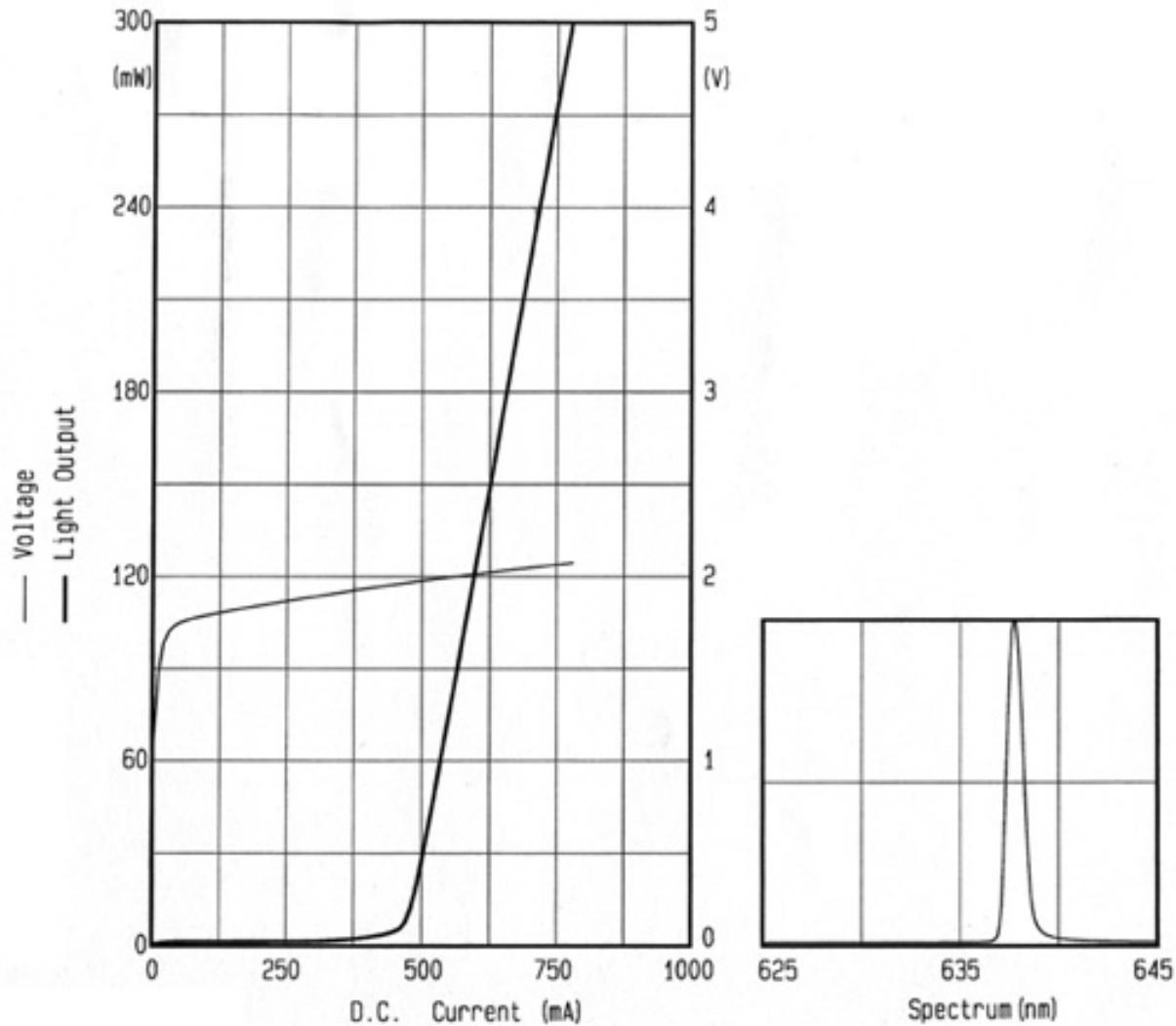
635nm LD 0.5W Power| C mount Pacakge| High Power

WSLD-635-500m-C

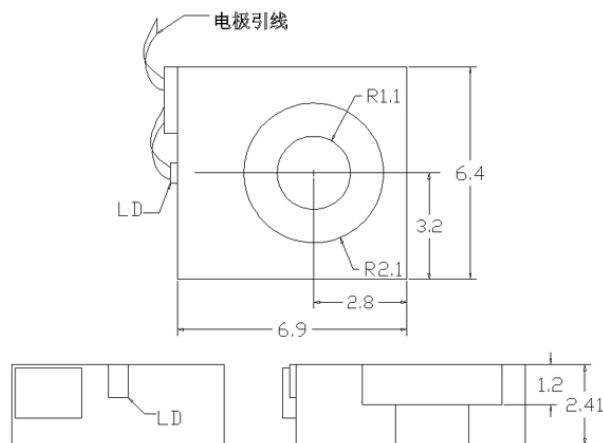
635nm Laser Diode 500mw		Wavespectrum Laser, Inc				
PARAMETER	SYMBOL	VALUE		UNIT		
Reverse Voltage	V_r	2.0		V		
Operating Temperature	T_{op}	+10~+25		°C		
Storage Temperature	T_{stg}	-40 ~ +85		°C		
Lead soldering temperature (10 sec.)	T_{is}	280		°C		
Features:	<ul style="list-style-type: none"> ● 635nm ● High power ,CW, Multi-mode ● High Quality ● C-mount package 					
Applications:	<ul style="list-style-type: none"> ● Medical laser treatment ● Laser indicator ● Laser detector 					
Specifications	WSLD-635-500m-C					
	Min	Type	Max			
Center Wavelength@25°C	630nm	635nm	642nm			
Spectral Width (FWHM)		1nm	2.5nm			
Output Power		500mW				
Emitter Area		150x1μm				
Beam Divergence (FWHM)				40°_± x 10°_{//}		
Temperature Coefficient of Wavelength		0.25nm / °C				
Slope Efficiency	0.80W/A	0.95W/A				
Threshold Current (Typ.)		0.75A	0.85A			
Operating Current (Typ.)		1.20A	1.35A			
Operating Voltage		2.2V	2.3V			
Package Style	C-mount					



Spectrum



C-mount Package View



Electrically shorten LD module and store in non-extreme conditions.

Suggest using the constant current power supply.

